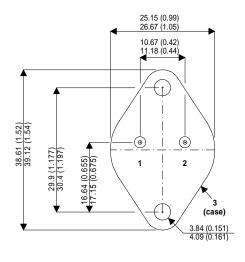


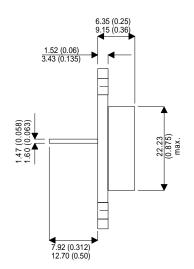


MECHANICAL DATA

Dimensions in mm(inches)

HIGH CURRENT NPN SILICON TRANSISTOR





FEATURES

- FAST SWITCHING
- HIGH PULSE POWER

APPLICATIONS

- POWER SWITCHING CIRCUITS
- MOTOR CONTROL

TO3 (TO204AE)

Pin 2 = Emitter Case = Collector Pin 1 = Base

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

V _{CBO}	Collector – Base Voltage (I _E = 0V)	350V
V_{CEO}	Collector - Emitter Voltage (I _B = 0V)	250V
V_{EBO}	Collector – Emitter Voltage (I _C = 0V)	10V
$I_{\mathbb{C}}$	Collector Current	60A
I _{CM}	Peak Collector Current (t _p = 10 ms)	80A
I_{B}	Base Current	16A
P_{tot}	Total Power Dissipation at T _{case} ≤ 25°C	350W
T _{stg} ,	Storage Temperature	-65°C to +200°C
T_{j}	Max. Operating Junction Temperature	200°C
$R_{\theta JC}$	Junction to Case Thermal Resistance	0.5°C/W

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V _{(BR)CEO*}	Collector - Emitter Breakdown Voltage	I _C = 200mA	I _B = 0	250			V
V _{(BR)EBO}	Emitter – Base Breakdown Voltage	I _C = 0	I _E = 10mA	10			V
I _{CEO}	Collector Emitter Cut-off Current	V _{CE} = 250V	I _B = 0			1.0	mA
I _{CBO}	Collector -Base Cut-off Current	V _{CE} = 350V	$I_{E} = 0$ $T_{C} = 125^{\circ}C$			0.2	mA
I _{EBO}	Emitter-Base Cut-off Current	I _C = 0	V _{EB} = 7V			0.2	mA
V _{CE(sat)*}	Collector – Emitter	I _C = 25A	I _B = 2A			1.0	V
	Saturation Voltage Base – Emitter	I _C = 40A	I _B = 4A		0.7	1.5	
V _{BE(sat)*}	Saturation Voltage	$I_{C} = 25A$ $I_{C} = 40A$	$I_B = 2A$ $I_B = 4A$		1.5	1.8 2	V
h _{FE}	DC Current Gain	I _C = 5A	$V_{CE} = 4V$	20		100	
		I _C = 40A	V _{CE} = 4V	15			
I _{S/b}	Second Breakdown Collector Current	V _{CE} = 20V	t = 1s	17.5			А
f _t	Transition Frequency	$I_C = 1.0A$ f = 1MHz	V _{CE} = 5V		10	16	MHz
t _{on}	Turn-On Time	$I_C = 40A$ $V_{CC} = 100V$	I _B = 4A		0.3	1.0	
t _f	Fall Time	I _C = 40A I _{B2} - 4A	I _{B1} =4A V _{CC} = 100V		0.2	0.6	μs
t _s	Storage Time	I _C = 40A I _{B2} - 4A	I _{B1} =4A V _{CC} = 100V		1.2	2	

^{*}Pulsed tp =300µs @< 1%

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